

ESD8451, SZESD8451

ESD Protection Diodes

Low Capacitance ESD Protection Diode for High Speed Data Line

The ESD8451 Series ESD protection diodes are designed to protect high speed data lines from ESD. Ultra-low capacitance and low ESD clamping voltage make this device an ideal solution for protecting voltage sensitive high speed data lines.

Features

- Low Capacitance (0.30 pF Max, I/O to GND)
- Protection for the Following IEC Standards:
IEC 61000-4-2 (Level 4)
ISO10605 330 pF / 2 kΩ ±30 kV Contact
- Low ESD Clamping Voltage
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- USB 3.0
- MHL 2.0
- eSATA

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Operating Junction Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Seconds)	T _L	260	°C
IEC 61000-4-2 Contact (ESD)	ESD	±15	kV
IEC 61000-4-2 Air (ESD)	ESD	±15	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

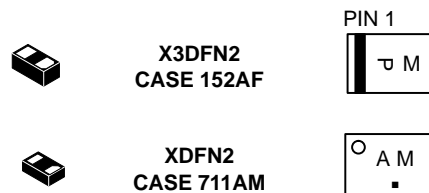
See Application Note AND8308/D for further description of survivability specs.



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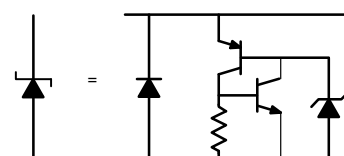
www.onsemi.com

MARKING DIAGRAMS



P, A = Specific Device Code
M = Date Code

PIN CONFIGURATION AND SCHEMATIC



ORDERING INFORMATION

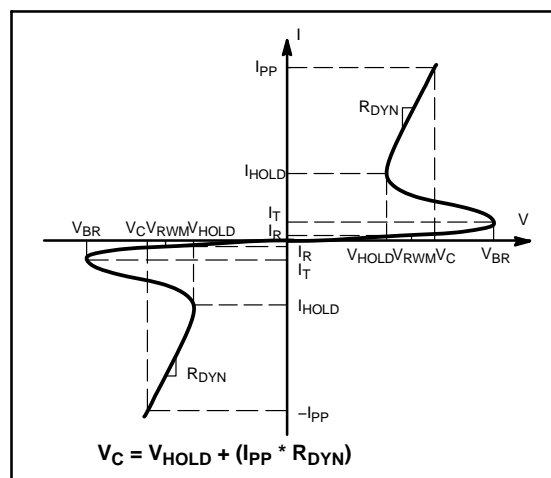
See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

ESD8451, SZESD8451

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter
V _{RWM}	Working Peak Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current
V _{HOLD}	Holding Reverse Voltage
I _{HOLD}	Holding Reverse Current
R _{DYN}	Dynamic Resistance
I _{PP}	Maximum Peak Pulse Current
V _C	Clamping Voltage @ I _{PP} V _C = V _{HOLD} + (I _{PP} * R _{DYN})



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}	I/O Pin to GND			3.3	V
Breakdown Voltage	V _{BR}	I _T = 1 mA, I/O Pin to GND	5.5	7.9	8.3	V
Reverse Leakage Current	I _R	V _{RWM} = 3.3 V, I/O Pin to GND			500	nA
Reverse Holding Voltage	V _{HOLD}	I/O Pin to GND		2.05		V
Holding Reverse Current	I _{HOLD}	I/O Pin to GND		17		mA
Clamping Voltage (Note 1)	V _C	IEC61000-4-2, ±8 kV Contact				V
ESD8451MUT5G Clamping Voltage	V _C	I _{PP} = 3.7 A, 8/20 μs pulse			13.7	V
ESD8451N2T5G Clamping Voltage	V _C	I _{PP} = 5.0 A, 8/20 μs pulse			17.0	V
ESD8451MUT5G Clamping Voltage TLP (Note 2)	V _C	I _{PP} = 8 A } IEC 61000-4-2 Level 2 equivalent (±4 kV Contact, ±4 kV Air) I _{PP} = 16 A } IEC 61000-4-2 Level 4 equivalent (±8 kV Contact, ±8 kV Air)		11.0 19.0		V
ESD8451N2T5G Clamping Voltage TLP (Note 2)	V _C	I _{PP} = 8 A } IEC 61000-4-2 Level 2 equivalent (±4 kV Contact, ±4 kV Air) I _{PP} = 16 A } IEC 61000-4-2 Level 4 equivalent (±8 kV Contact, ±8 kV Air)		9.0 16.0		V
ESD8451MUT5G Dynamic Resistance	R _{DYN}	Pin1 to Pin2 Pin2 to Pin1		1.0 1.0		Ω
ESD8451N2T5G Dynamic Resistance	R _{DYN}	Pin1 to Pin2 Pin2 to Pin1		0.84 0.84		Ω
Junction Capacitance	C _J	V _R = 0 V, f = 1 MHz		0.20	0.30	pF
Junction Capacitance	C _J	V _R = 0 V, f = 2.5 GHz		0.19	0.25	pF

- For test procedure see Figure 16 and application note AND8307/D.
- ANSI/ESD STM5.5.1 – Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model.
TLP conditions: Z₀ = 50 Ω, t_p = 100 ns, t_r = 4 ns, averaging window; t₁ = 30 ns to t₂ = 60 ns.

ESD8451, SZESD8451

TYPICAL CHARACTERISTICS

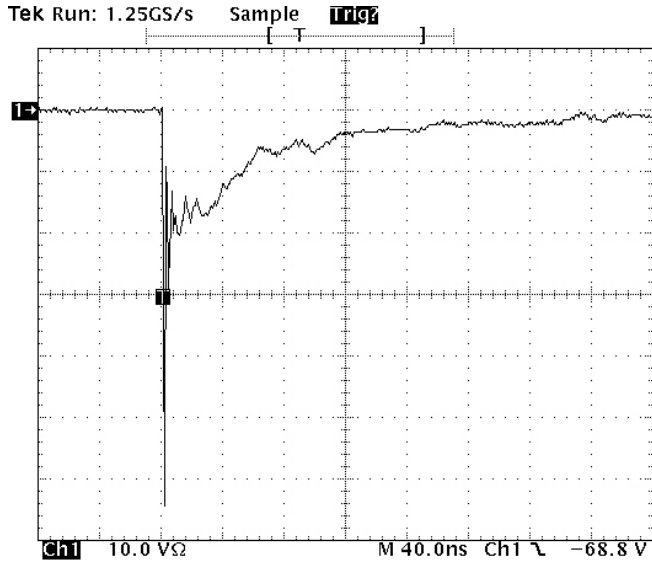


Figure 1. ESD8451N2 ESD Clamping Voltage Screenshot Negative 8kV Contact per IEC61000-4-2

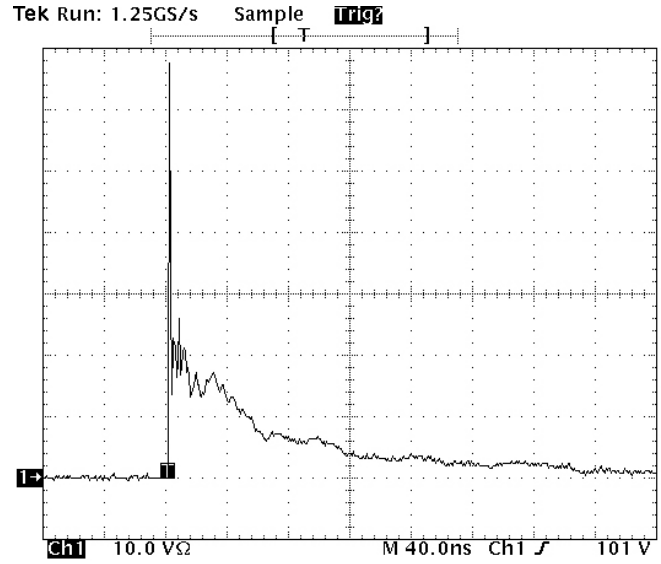


Figure 2. ESD8451N2 ESD Clamping Voltage Screenshot Positive 8kV Contact per IEC61000-4-2

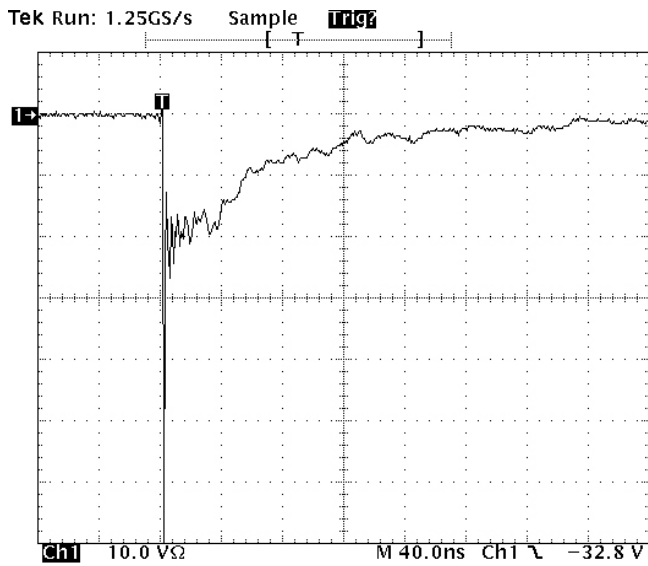


Figure 3. ESD8451MU ESD Clamping Voltage Screenshot Negative 8kV Contact per IEC61000-4-2

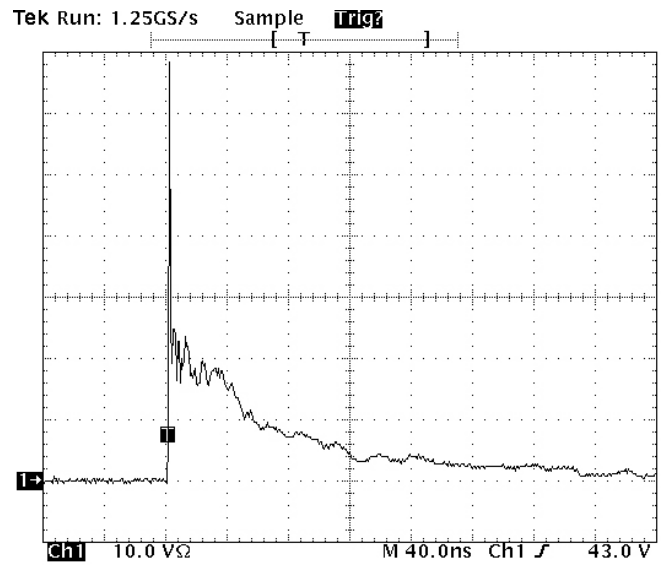


Figure 4. ESD8451MU ESD Clamping Voltage Screenshot Positive 8kV Contact per IEC61000-4-2

ESD8451, SZESD8451

TYPICAL CHARACTERISTICS

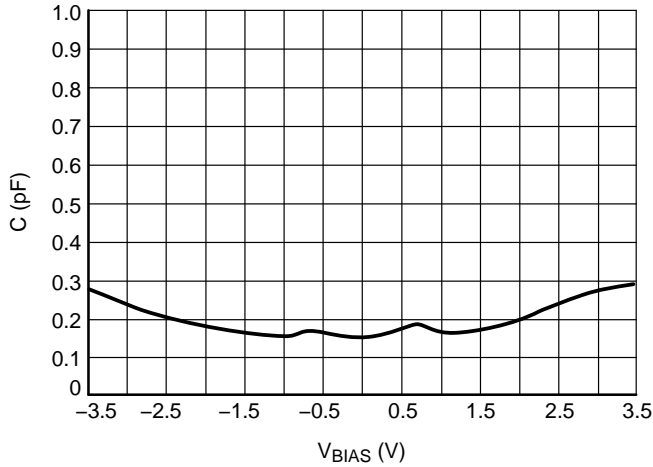


Figure 5. ESD8451MUT5G CV Characteristics

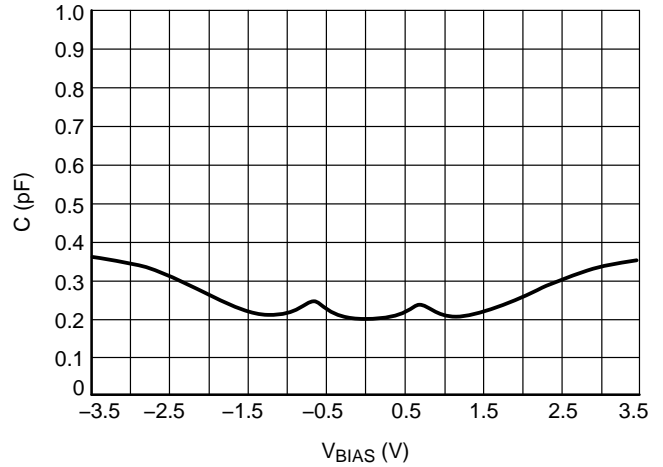


Figure 6. ESD8451N2T5G CV Characteristics

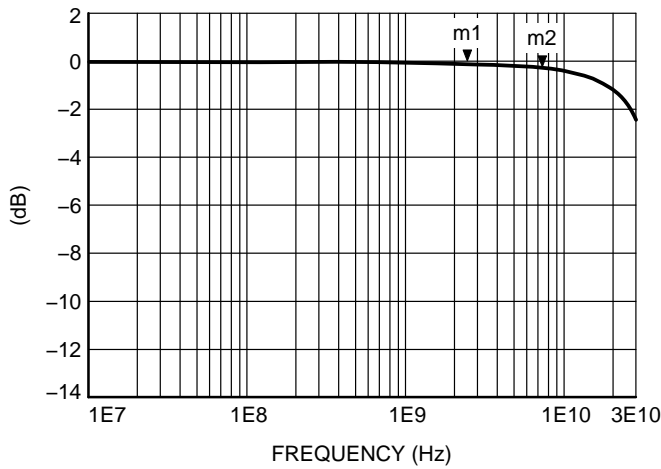


Figure 7. ESD8451MUT5G S21 Insertion Loss

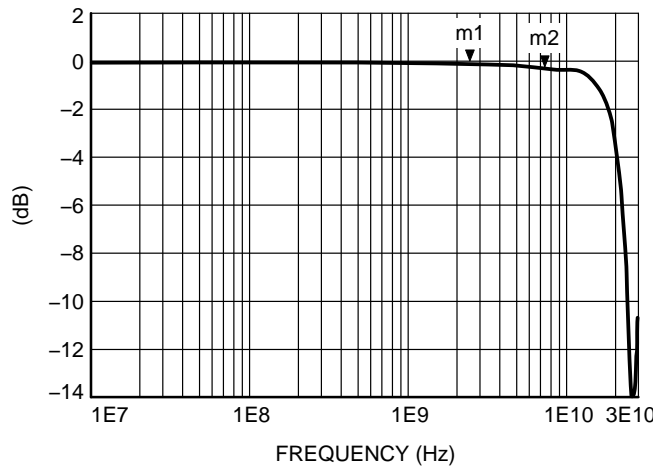


Figure 8. ESD8451N2T5G S21 Insertion Loss

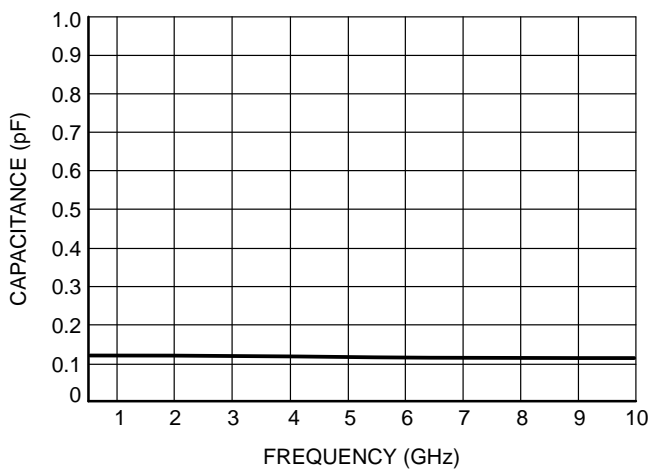


Figure 9. ESD8451MUT5G Capacitance over Frequency

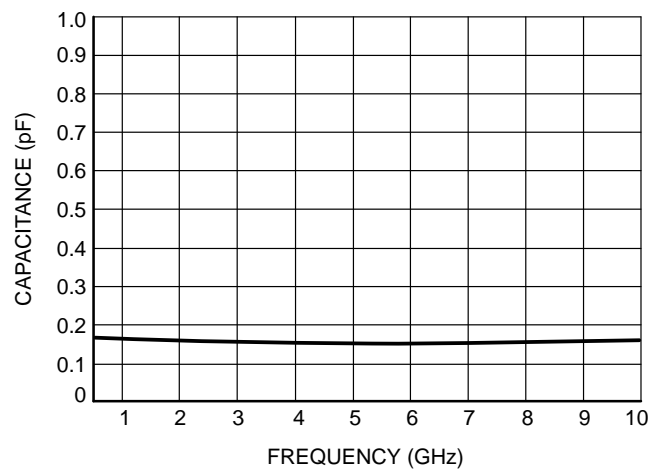


Figure 10. ESD8451N2T5G Capacitance over Frequency

ESD8451, SZESD8451

TYPICAL CHARACTERISTICS

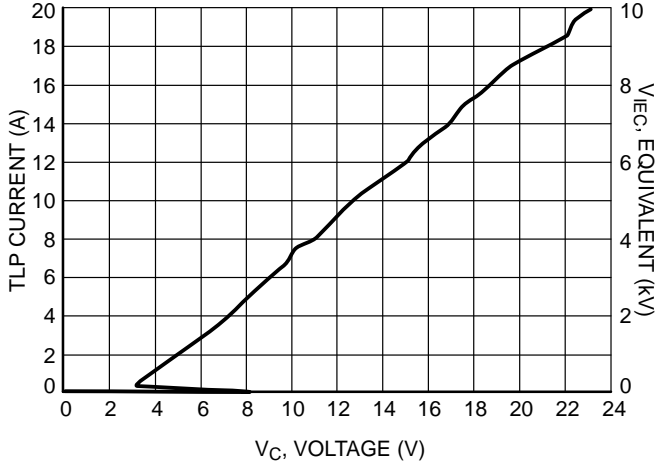


Figure 11. ESD8451MUT5G Positive TLP I-V Curve

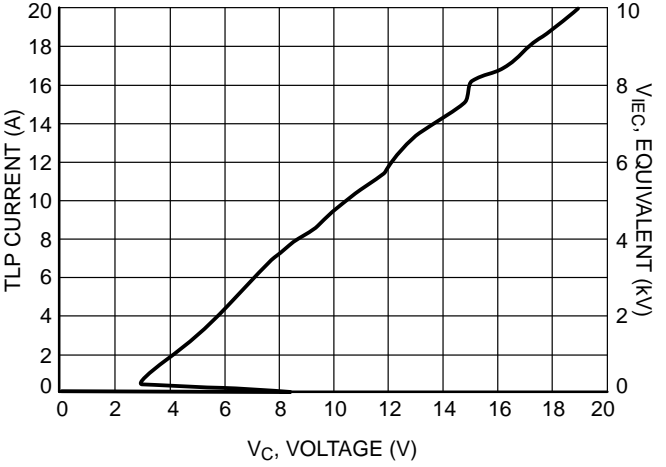


Figure 12. ESD8451N2T5G Positive TLP I-V Curve

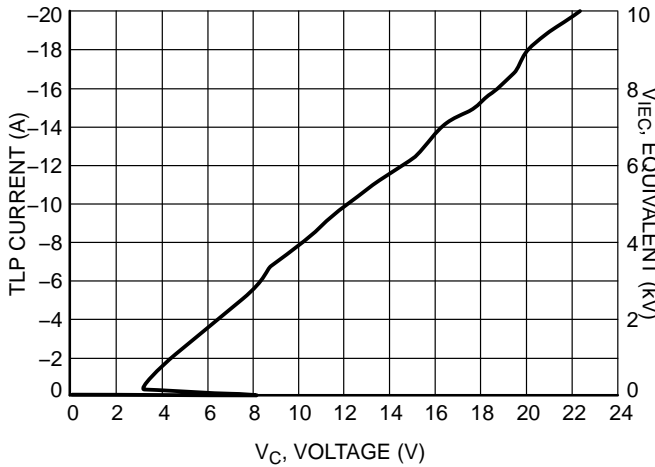


Figure 13. ESD8451MUT5G Negative TLP I-V Curve

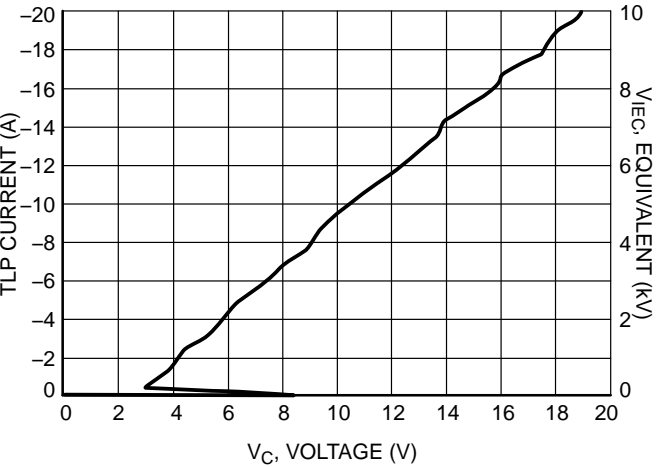


Figure 14. ESD8451N2T5G Negative TLP I-V Curve

ESD8451, SZESD8451

Latch-Up Considerations

ON Semiconductor's 8000 series of ESD protection devices utilize a snap-back, SCR type structure. By using this technology, the potential for a latch-up condition was taken into account by performing load line analyses of common high speed serial interfaces. Example load lines for latch-up free applications and applications with the potential for latch-up are shown below with a generic IV characteristic of a snapback, SCR type structured device overlaid on each. In the latch-up free load line case, the IV characteristic of the snapback protection device intersects the load-line in one unique point (V_{OP} , I_{OP}). This is the only

stable operating point of the circuit and the system is therefore latch-up free. In the non-latch up free load line case, the IV characteristic of the snapback protection device intersects the load-line in two points (V_{OPA} , I_{OPA}) and (V_{OPB} , I_{OPB}). Therefore in this case, the potential for latch-up exists if the system settles at (V_{OPB} , I_{OPB}) after a transient. Because of this, ESD8451 should not be used for HDMI applications – ESD8104 or ESD8040 have been designed to be acceptable for HDMI applications without latch-up. Please refer to Application Note AND9116/D for a more in-depth explanation of latch-up considerations using ESD8000 series devices.

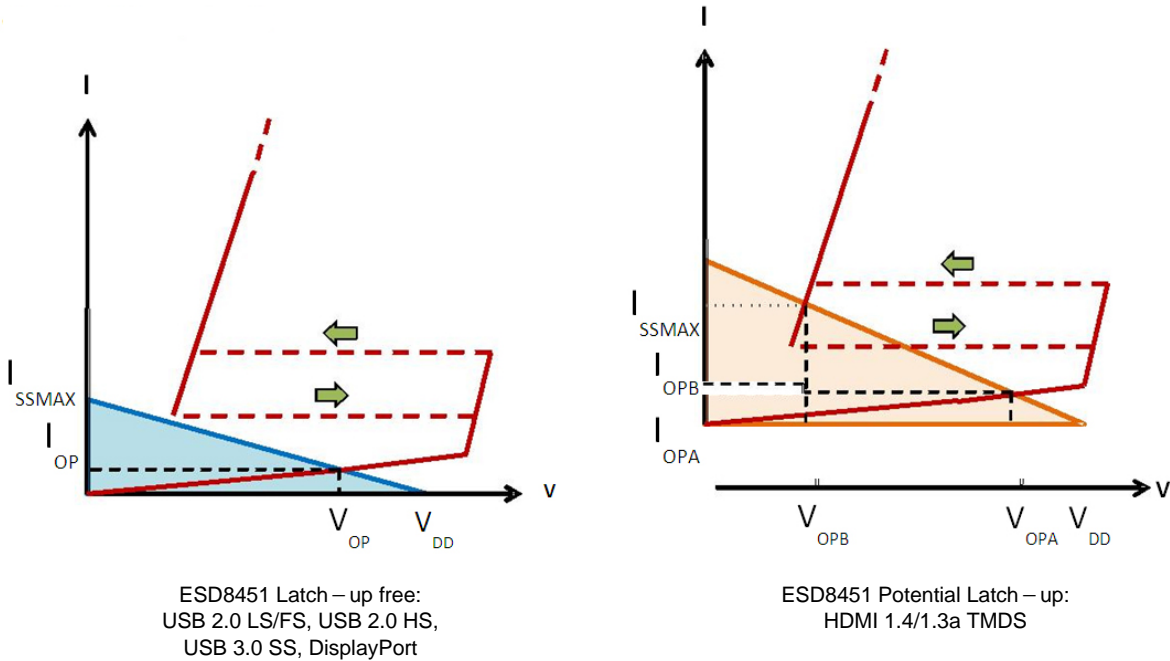


Figure 15. Example Load Lines for Latch-up Free Applications and Applications with the Potential for Latch-up

Table 1. SUMMARY OF SCR REQUIREMENTS FOR LATCH-UP FREE APPLICATIONS

Application	VBR (min) (V)	IH (min) (mA)	VH (min) (V)	ON Semiconductor ESD8000 Series Recommended PN
HDMI 1.4/1.3a TMDS	3.465	54.78	1.0	ESD8104, ESD8040
USB 2.0 LS/FS	3.301	1.76	1.0	ESD8004, ESD8451
USB 2.0 HS	0.482	N/A	1.0	ESD8004, ESD8451
USB 3.0 SS	2.800	N/A	1.0	ESD8004, ESD8006, ESD8451
DisplayPort	3.600	25.00	1.0	ESD8004, ESD8006, ESD8451

ESD8451, SZESD8451

IEC 61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

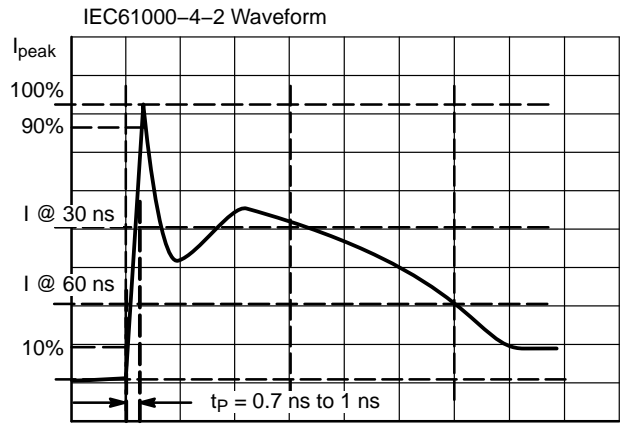


Figure 16. IEC61000-4-2 Spec

Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I-V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 17. TLP I-V curves of ESD protection devices accurately demonstrate the product’s ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 18 where an 8 kV IEC 61000-4-2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I-V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels.

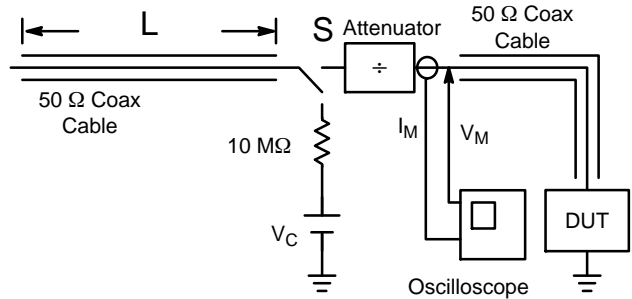


Figure 17. Simplified Schematic of a Typical TLP System

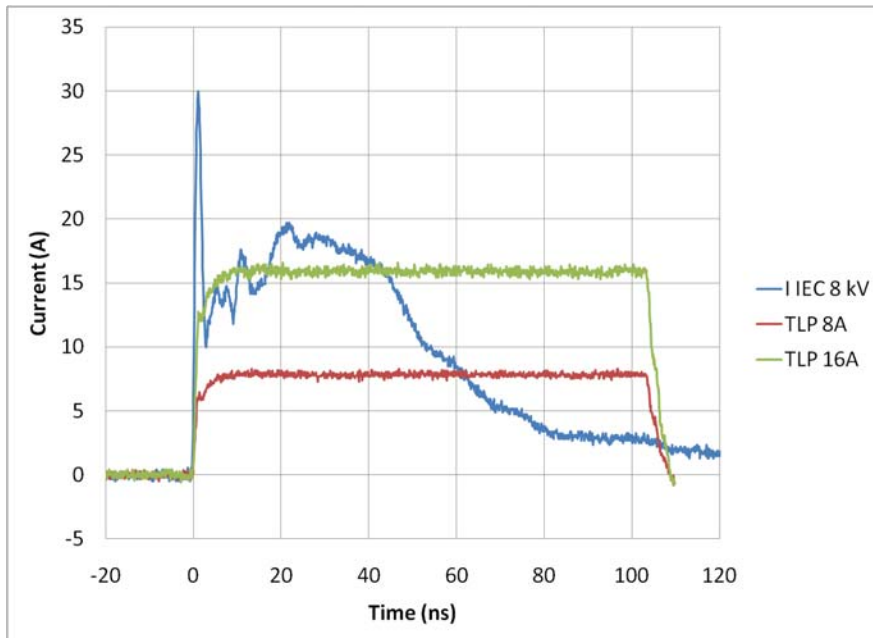


Figure 18. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms

ESD8451, SZESD8451

ORDERING INFORMATION

Device	Package	Shipping†
ESD8451N2T5G, SZESD8451N2T5G*	XDFN2 (Pb-Free)	8000 / Tape & Reel
ESD8451MUT5G	X3DFN2 (Pb-Free)	10000 / Tape & Reel
SZESD8451MUT5G*	X3DFN2 (Pb-Free)	15000 / Tape & Reel

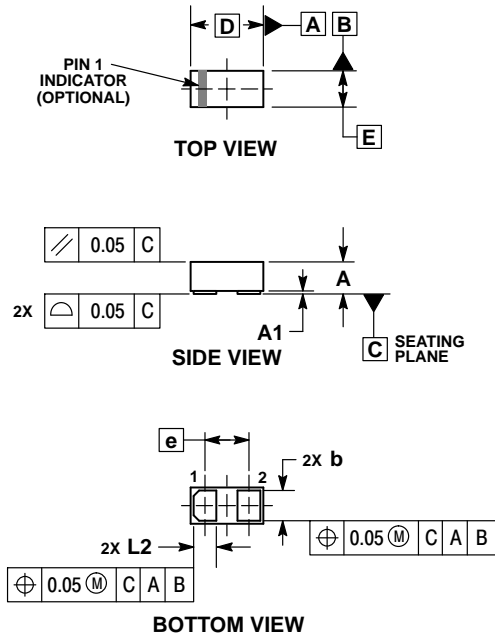
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

ESD8451, SZESD8451

PACKAGE DIMENSIONS

X3DFN2, 0.62x0.32, 0.355P, (0201)
CASE 152AF
ISSUE A

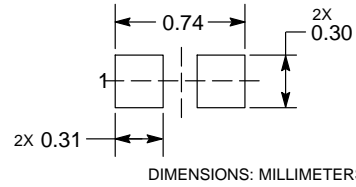


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.

MILLIMETERS		
DIM	MIN	MAX
A	0.25	0.33
A1	—	0.05
b	0.22	0.28
D	0.58	0.66
E	0.28	0.36
e	0.355 BSC	
L2	0.17	0.23

RECOMMENDED MOUNTING FOOTPRINT*

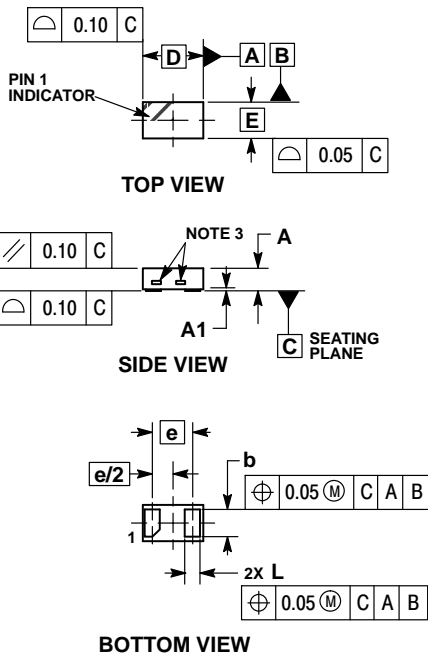


See Application Note AND8398/D for more mounting details
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ESD8451, SZESD8451

PACKAGE DIMENSIONS

XDFN2 1.0x0.6, 0.65P (SOD-882)
CASE 711AM
ISSUE O

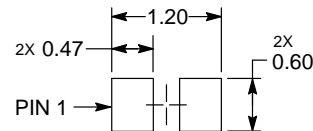


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. EXPOSED COPPER ALLOWED AS SHOWN.

MILLIMETERS		
DIM	MIN	MAX
A	0.34	0.44
A1	---	0.05
b	0.43	0.53
D	1.00 BSC	
E	0.60 BSC	
e	0.65 BSC	
L	0.20	0.30

**RECOMMENDED
SOLDER FOOTPRINT***



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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